

DECLARATION

As a below named inventor, I declare that:

My residence, post office address and citizenship are as stated below next to my name; I believe I am the original, first and joint inventor of the subject matter which is claimed and for which a patent is sought on the invention entitled: HIGH VOLTAGE MOS DEVICES WITH HIGH GATED-DIODE BREAKDOWN VOLTAGE AND PUNCH-THROUGH VOLTAGE, the specification of which is attached hereto.

I have reviewed and understand the contents of the above identified specification, including the claims, as amended by any amendment referred to above. I acknowledge the duty to disclose information which is material to the examination of this application in accordance with Title 37, Code of Federal Regulations, Section 1.56. I claim foreign priority benefits under Title 35, United States Code, Section 119 of any foreign application(s) for patent or inventor's certificate listed below and have also identified below any foreign application for patent or inventor's certificate having a filing date before that of the application on which priority is claimed.

Prior Foreign Application(s)

Country	Application No.	Date of Filing	Priority Claimed Under 35 USC 119
			Yes ____ No ____

I hereby claim the benefit under Title 35, United States Code § 119(e) of any United States provisional application(s) listed below:

Application No.	Filing Date
60/024,927	August 30, 1996
60/025,843	September 6, 1996

I claim the benefit under Title 35, United States Code, Section 120 of any United States application(s) listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of Title 35, United States Code, Section 112, I acknowledge the duty to disclose material information as defined in Title 37, Code of Federal Regulations, Section 1.56 which occurred between the filing date of the prior application and the national or PCT international filing date of this application:

Application No.	Date of Filing	Status
		____ Patented ____ Pending ____ Abandoned

Full Name of Inventor 1	Last Name	First Name	Middle Name or Initial
	MADURAWA	RAMINDA	U.
Residence & Citizenship	City	State/Foreign Country	Country of Citizenship
	Sunnyvale	California	Sri Lanka
Post Office Address	Post Office Address	City	State/Country
	882 Louise Drive	Sunnyvale	California
Zip Code	Full Name of Inventor 2	Last Name	First Name
94087		LIU	DAVID
Middle Name or Initial	Residence & Citizenship	City	State/Foreign Country
K.Y.		Fremont	California
Country of Citizenship	Post Office Address	City	State/Country
United States of America	470 Tumbleweed Court	Fremont	California
Zip Code	Post Office Address	City	State/Country
94539			

THE UNIVERSITY OF CHICAGO

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Prior Foreign Application(s)

Country	Application No.	Date of Filing	Priority Claimed Under 35 USC 119
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Application No.	Date of Filing	Status
		____ Patented ____ Pending ____ Abandoned

Full Name of Inventor 1	Last Name MADURAW E	First Name RAMINDA	Middle Name or Initial U.	
Residence & Citizenship	City Sunnyvale	State/Foreign Country California	Country of Citizenship Sri Lanka	
Post Office Address	Post Office Address 882 Louise Drive	City Sunnyvale	State/Country California	Zip Code 94087
Full Name of Inventor 2	Last Name LIU	First Name DAVID	Middle Name or Initial K.Y.	
Residence & Citizenship	City Fremont	State/Foreign Country Calif rnia	Country of Citizenship United States of America	
Post Office Address	Post Office Address 470 Tumbleweed C urt	City Frem nt	State/Country California	Zip Code 94539

POWER OF ATTORNEY BY ASSIGNEE

ASSIGNEE, ALTERA CORPORATION, with offices located at 101 Innovation Drive, San Jose, California 95134, is the Assignee of the invention entitled: HIGH VOLTAGE MOS DEVICES WITH HIGH GATED-DIODE BREAKDOWN VOLTAGE AND PUNCH-THROUGH VOLTAGE, the specification of which was filed on August 29, 1997 as Application No. 08/920,377.

The Assignment accompanying this Power of Attorney has been reviewed by the undersigned. The undersigned certifies that to the best of the undersigned's knowledge and belief, title is in the Assignee. The undersigned (whose title is supplied below) is empowered to act on behalf of the Assignee.

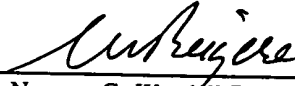
Assignee hereby appoints the following attorneys and/or agents to prosecute this application and transact all business in the Patent and Trademark Office connected therewith.

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ALTERA CORPORATION

Date: 3/23/98

**By: 
Name: C. Wendell Bergere
Title: Vice President, General Counsel and Secretary

**By: _____
Name: Paul Newhagen
Title: Vice President, Administration

** Only one signature is required.

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